

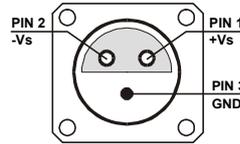
10 MHz High Input Impedance Voltage Amplifier



<p>Features</p>	<ul style="list-style-type: none"> • Switchable Gain 40/60 dB (x100 / x1,000) • Bandwidth DC ... 10 MHz • High Input Impedance 1 MΩ • Switchable AC/DC Coupling 															
<p>Applications</p>	<ul style="list-style-type: none"> • Oscilloscope and Transient Recorder Pre-amplifier • Photomultiplier and Microchannel Plate Amplifier • Signal Booster for Optical Receivers and Current Amplifiers • Time-Resolved Pulse and Transient Measurements 															
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Specifications (continued) Temperature Range	Storage Temperature Operating Temperature	- 40 ... + 100 °C 0 ... + 60 °C
Absolute Maximum Ratings	Power Supply Voltage Signal Input Voltage Transient Input Voltage	± 20 V ± 5 V 200 V (out of a 200 pF Source)
Connectors	Input Output Power Supply	BNC BNC LEMO series 1S, 3-pin fixed socket Pin 1: + 15V Pin 2: - 15V Pin 3: GND



Dimensions	<p style="text-align: center;">all measures in mm unless otherwise noted</p> <p style="text-align: right;">DZ_HVA-10M-60_R2</p>	
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